SIKA e-SiC[®] 3.5N 70F Product information



High-purity silicon carbide powder for semiconductor and electronic applications

High-purity silicon carbide, manufactured using the Acheson process, is utilized in the semiconductor industry for a wide range of components and devices, including wafer boats, paddles, tubes, flanges, and more.

Typical chemistry

Char. description	Unit	Value
Free C	%	0,02
Free Si	%	0,07
Total O ₂	%	0,05
AI	ppm	110
Fe	ppm	100
Ni	ppm	25
v	ppm	33
Ті	ppm	7,5
В	ppm	1,2
Cr	ppm	<0,3
Cu	ppm	0,16
S	ppm	2,1
Zn	ppm	1
Li	ppm	<0,05

Particle size distribution – laser technique

Char. description	Unit	Value
d10%	μm	312
d50%	μm	226
d90%	μm	164

Analytical procedures:

All measurement is in accordance to FEPA, ANSI or JIS, or other methods in agreement with customers. Trace element analysis by GDMS

Packaging:

25 kg paper bags

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